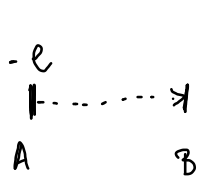


Cariche positive si muovono verso i pot. all' Crescenti.
 = negative = = = " " crescenti



$$V_B - V_A = 1 \text{ V}$$

$$K_B - K_A = -q \Delta V = 1.6 \cdot 10^{-19} \text{ C} \cdot \text{V} = 1.6 \cdot 10^{-19} \text{ e} \cdot \frac{\text{J}}{\text{e}} = 1.6 \cdot 10^{-19} \text{ J}$$

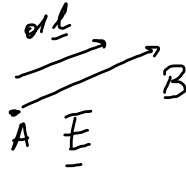
Se $K_A = 0$ (el. inizialmente fermo)
 $q_e = -1.6 \cdot 10^{-19} \text{ C}$

$$K = 1.6 \cdot 10^{-19} \text{ J} \stackrel{\text{def}}{=} 1 \text{ eV}$$

1 eV ^{cinetica} è acquisita da un elettrone quando si muove spontaneamente tra 2 pot. con d.d.p. di 1 V

$$\Delta V_{AB} = - \int_A^B \underline{E} \cdot d\underline{l}$$

Se $\underline{E} = \text{const}$



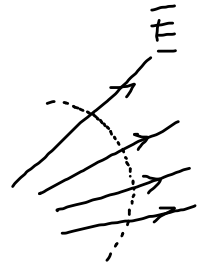
Sceglia $d\underline{l} \parallel \underline{E}$

$$\underline{E} \cdot d\underline{l} = E dl$$

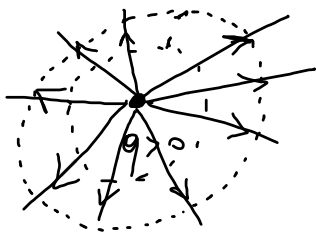
$$\Delta V_{AB} = V_B - V_A = - \int_A^B \underline{E} \cdot d\underline{l} = - E \int_A^B dl = - E d_{AB}$$

E uniforme

$\Delta V_{AB} = 0$ se $\underline{E} \perp d\underline{l}$
perché, in questo caso, $\underline{E} \cdot d\underline{l} = 0$



Le sup. equipotenziali sono il luogo dei punti \perp alle linee di campo



Sup. equipotenziali per la carica p[er]iforme sono sfere centrate nella carica q

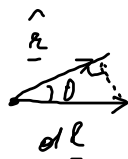
Carica p[er]iforme

$$\Delta V_{AB} = - \int_A^B \underline{E} \cdot d\underline{l}$$

carica p[er]iforme

$$\underline{E} = k_e \frac{q}{r^2} \hat{r}$$

$$d\underline{l} \cdot \hat{r} = (\text{proiezione di } d\underline{l} \text{ su } \hat{r}) \cdot |\hat{r}|$$



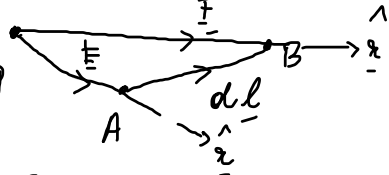
$$= - \int_A^B k_e \frac{q}{r^2} \hat{r} \cdot d\underline{l}$$

$$= 1 \cdot d\pi$$

$$= - \int_{r_A}^{r_B} k_e \frac{q}{r^2} dr$$

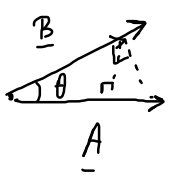
$$= -k_e q \left[-\frac{1}{r} \right]_{r_A}^{r_B}$$

$$= -k_e q \left[-\frac{1}{r_B} + \frac{1}{r_A} \right]$$



$$\rightarrow k_e q \left(\frac{1}{r_B} - \frac{1}{r_A} \right)$$

$$\underline{A} \cdot \underline{B} = |\underline{A}| |\underline{B}| \cos \theta = (\text{proiezione di } \underline{A} \text{ su } \underline{B}) \cdot |\underline{B}| =$$



$$= (\text{proiezione di } \underline{B} \text{ su } \underline{A}) \cdot |\underline{A}|$$

$$\underline{dl} \cdot \underline{\hat{r}} = (\text{proiezione di } \underline{dl} \text{ su } \underline{\hat{r}}) \cdot |\underline{\hat{r}}|$$

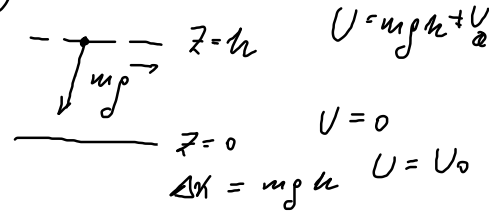
$$\underline{A} \cdot \underline{B} = dr \cdot 1 = dr$$

$$V_B - V_A = k_e q \left[\frac{1}{r_B} - \frac{1}{r_A} \right]$$

Supponiamo $r_A \rightarrow +\infty$
 d.d.p. tra un punto B a dist. finita da q
 e un punto A all'infinito

Scego $V_A = 0$ ($r_A \rightarrow +\infty$) $V_B - V_A = \frac{k_e q}{r_B}$

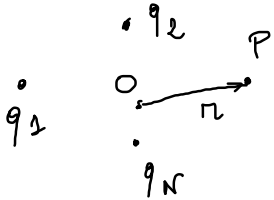
$$V_B = \frac{k_e q}{r_B}$$



Potenziale della carica q in un pto P
 distante r da q

$$V(r) = \frac{k_e q}{r} \quad (\text{Oss } V(+\infty) = 0)$$

Pr. sovrapposizione per potenziali



$$\underline{E}(P) = \sum_{i=1}^N \underline{E}_i(P)$$

pr. sovrapp.

pr. sovr. per \underline{E}

$$V(P) = - \int_{\infty}^r \underline{E} \cdot d\underline{l} = - \int_{\infty}^r \sum_{i=1}^N \underline{E}_i(r) \cdot d\underline{l}$$

$$V(\infty) = 0$$

$$= \sum_{i=1}^N \left[- \int_{\infty}^r \underline{E}_i(r) \cdot d\underline{l} \right]$$

$V_{q_i}(r)$: pot. prodotto da q_i

$$= \sum_{i=1}^N V_{q_i}(r)$$



$$Q \approx \sum_{i=1}^N \Delta q_i \rightarrow \int \Delta q$$

Δq_i : molto piccolo

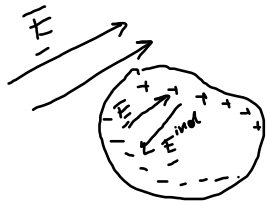
$$V_Q(\pi) \approx \sum_{i=1}^N \frac{\kappa_i \Delta q_i}{\pi} \rightarrow \int \frac{\kappa_e \Delta q}{\pi}$$

$\Delta q_i = \frac{Q}{N}$
 $N \rightarrow +\infty$ volume occupato da Q
 $\Delta q_i \rightarrow \Delta q$

$$\underline{E(\pi)} = -\underline{\nabla} V(\pi)$$

$$\underline{\nabla} f = \left[\frac{\partial f}{\partial x} \hat{i} + \frac{\partial f}{\partial y} \hat{j} + \frac{\partial f}{\partial z} \hat{k} \right]$$

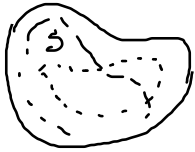
Proprietà dei conduttori ideali all'eq. elettrostatica



All'equilibrio statico sono valide

$$\begin{aligned}\underline{\Sigma F} &= 0 & \underline{\Sigma qE} &= 0 \Rightarrow \underline{\Sigma E} = 0 \\ \underline{E}_{\text{Tot}} &= 0\end{aligned}$$

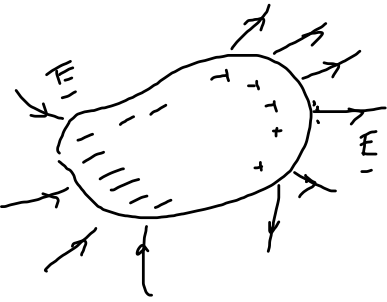
Distrib. carica all'equilibrio



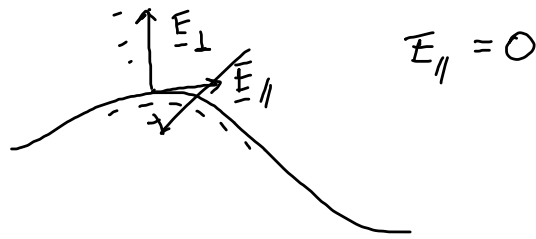
S è una generica sp. di Gauss dentro il conduttore

$$\int_S \underline{E} \cdot d\underline{S} = 0 \Rightarrow q^{\text{int}} = 0$$

q è solo in superficie



\underline{E} vicino alla sup. conduttore?



$$E_{\parallel} = 0$$

\underline{E} vicino al conduttore
è solo \perp sup.

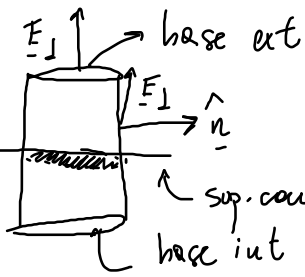
Appl. Th Gauss S : cilindretto "ufforato" al pto
che considero

1 Base esterna al conduttore

1 = dentro il conduttore

Cilindro sup. lat. \perp sup. conduttore

$$\int_S \underline{E} \cdot d\underline{S} = \int_{\text{base ext}} \underline{E} \cdot d\underline{S} + \int_{\text{base int}} \underline{E} \cdot d\underline{S} + \int_{\text{sup. lat.}} \underline{E} \cdot d\underline{S}$$



$$\int_{\text{base int}} \vec{E} \cdot d\vec{S} = 0 \quad \text{perché } \vec{E} = \vec{0} \text{ nel conduttore}$$

Sulla sup. laterale $\vec{E} \cdot \hat{n} = 0 \Rightarrow \int_{\text{sup. lat.}} \vec{E} \cdot d\vec{S} = 0$

cilindro "piccolo" \hat{n} è // alla sup. conduttore

$$\int_{\text{base ext}} \vec{E} \cdot d\vec{S} = \int E dS = E \int_{\text{base ext}} dS = E \cdot A = \frac{Q^{\text{caric.}}}{\epsilon_0} ; E = \frac{Q^{\text{caric.}}}{A \epsilon_0} = \frac{\sigma}{\epsilon_0}$$

$\vec{E} \parallel \hat{n} \Rightarrow \vec{E} \cdot d\vec{S} = E dS$ th Gauss σ : dens. di carica

$$\Delta V = - \int_A^B \vec{E} \cdot d\vec{l} = 0 \Rightarrow V = \text{const}$$

$\vec{E} = \vec{0}$



sup. $\left[\frac{C}{m^2} \right]$ vicino al p.t.o.